

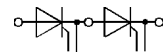
SEMIPACK® 5 Thyristor Modules

SKKT 500

Preliminary Data

V_{RS}	V_{RRM}	$(dv/dt)_{cr}$	I_{TRMS} (maximum values for continuous operation)
	V_{DRM}		920 A
V	V	V/ μ s	I_{TAV} (sin. 180; $T_{case} = 80\text{ }^{\circ}\text{C}$)
			585 A
900	800	500	SKKT 500/08 D
1300	1200	1000	SKKT 500/12 E
1500	1400	1000	SKKT 500/14 E
1700	1600	1000	SKKT 500/16 E
1900	1800	1000	SKKT 500/18 E

Symbol	Conditions	SKKT 500	Units
I_{TAV}	sin. 180; $T_{case} = 85\text{ }^{\circ}\text{C}$	540	A
	$T_{case} = 89\text{ }^{\circ}\text{C}$	500	A
I_D	B2/B6 T_{amb} P 16/200 F	665 / 845	A
I_{RMS}	W1/W3 $= 35\text{ }^{\circ}\text{C}$ P 16/300 F	850 / 3 x 670	A
I_{TSM}	$T_{vj} = 25\text{ }^{\circ}\text{C}$; 10 ms	17 000	A
	$T_{vj} = 130\text{ }^{\circ}\text{C}$; 10 ms	15 000	A
i^2t	$T_{vj} = 25\text{ }^{\circ}\text{C}$; 8,3 ... 10 ms	1 445 000	A ² s
	$T_{vj} = 130\text{ }^{\circ}\text{C}$; 8,3 ... 10 ms	1 125 000	A ² s
t_{gd}	$T_{vj} = 25\text{ }^{\circ}\text{C}$ $I_G = 1\text{ A}$	1	μ s
	$di_G/dt = 1\text{ A}/\mu\text{s}$	2	μ s
t_{gr}	$V_D = 0,67 \cdot V_{DRM}$		
$(di/dt)_{cr}$	$T_{vj} = 130\text{ }^{\circ}\text{C}$	200	A/ μ s
t_q	$T_{vj} = 130\text{ }^{\circ}\text{C}$	typ. 100 ... 200	μ s
I_H	$T_{vj} = 25\text{ }^{\circ}\text{C}$; typ./max.	150 / 500	mA
I_L	$T_{vj} = 25\text{ }^{\circ}\text{C}$; $R_G = 33\text{ }\Omega$; typ./max.	0,3 / 2	A
V_T	$T_{vj} = 25\text{ }^{\circ}\text{C}$; $I_T = 1700\text{ A}$	max. 1,5	V
$V_{T(TO)}$	$T_{vj} = 130\text{ }^{\circ}\text{C}$	0,925	V
r_T	$T_{vj} = 130\text{ }^{\circ}\text{C}$	0,27	m Ω
I_{DD} ; I_{RD}	$T_{vj} = 130\text{ }^{\circ}\text{C}$; $V_{RD} = V_{RRM}$ $V_{DD} = V_{DRM}$	100	mA
V_{GT}	$T_{vj} = 25\text{ }^{\circ}\text{C}$; d.c.	3	V
I_{GT}	$T_{vj} = 25\text{ }^{\circ}\text{C}$; d.c.	200	mA
V_{GD}	$T_{vj} = 130\text{ }^{\circ}\text{C}$; d.c.	0,25	V
I_{GD}	$T_{vj} = 130\text{ }^{\circ}\text{C}$; d.c.	10	mA
R_{thjc}	cont. $\left. \begin{array}{l} \text{sin. 180} \\ \text{rec. 120} \end{array} \right\} \text{ per thyristor / per module}$	0,062 / 0,031 0,065 / 0,0325 0,070 / 0,035	$^{\circ}\text{C}/\text{W}$ $^{\circ}\text{C}/\text{W}$ $^{\circ}\text{C}/\text{W}$
R_{thch}		0,02 / 0,01	$^{\circ}\text{C}/\text{W}$
T_{vj}		- 40 ... + 130	$^{\circ}\text{C}$
T_{stg}		- 40 ... + 130	$^{\circ}\text{C}$
V_{isol}	a. c. 50 Hz; r.m.s.; 1 s/1 min	3600/3000	V~
M_1	to heatsink (M6) SI units	$5 \pm 15\text{ }\%$ ¹⁾	Nm
	US units	$44 \pm 15\text{ }\%$ ¹⁾	lb.in.
M_2	to terminals (M10) SI units	$12 \pm 15\text{ }\%$ ²⁾	Nm
	US units	$106 \pm 15\text{ }\%$ ²⁾	lb.in.
a		$5 \cdot 9,81$	m/s ²
w	approx.	1420	g
Case		A 60	



SKKT

Features

- Heat transfer through aluminium nitride ceramic isolated metal baseplate
- Precise metal pressure contacts for high reliability
- UL recognition applied for: file no. E 63 632

Typical Applications

- AC motor starters
- Input converters for AC inverter drives
- DC motor control (e.g. for machine tools)
- Temperature control (e.g. for ovens, chemical processes)

¹⁾ See the assembly instructions

²⁾ The screws must be lubricated

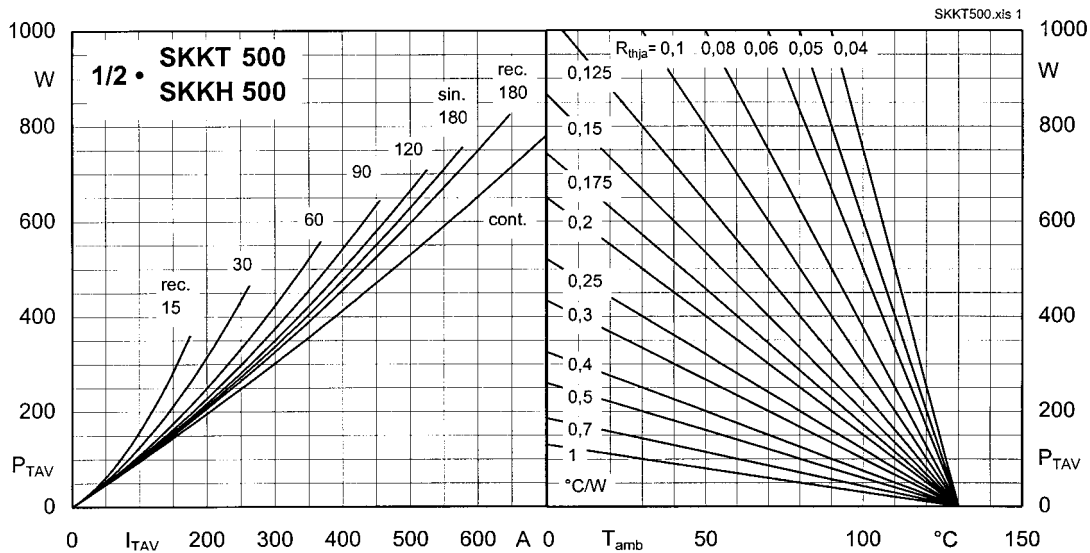


Fig. 1 Power dissipation per thyristor vs. on-state current and ambient temperature

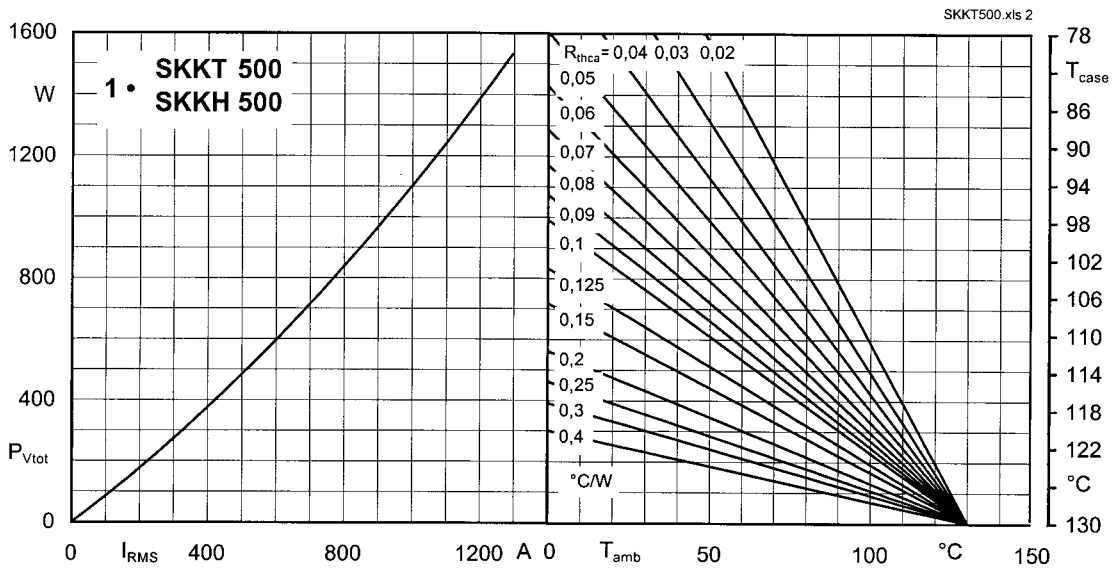


Fig. 2 Power dissipation per module vs. rms current and case temperature

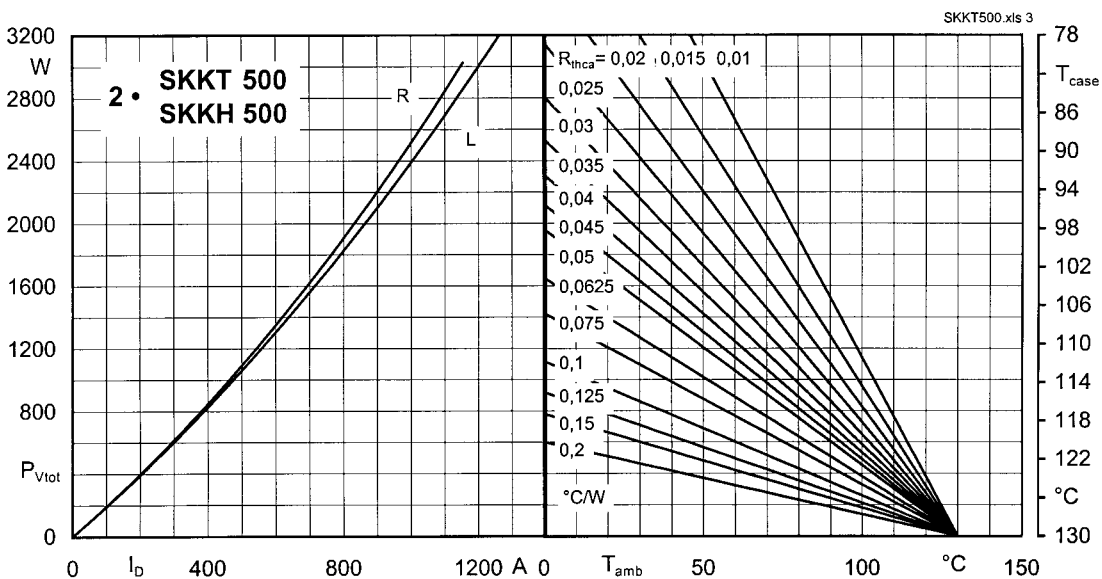


Fig. 3 Power dissipation of two module vs. direct current and case temperature

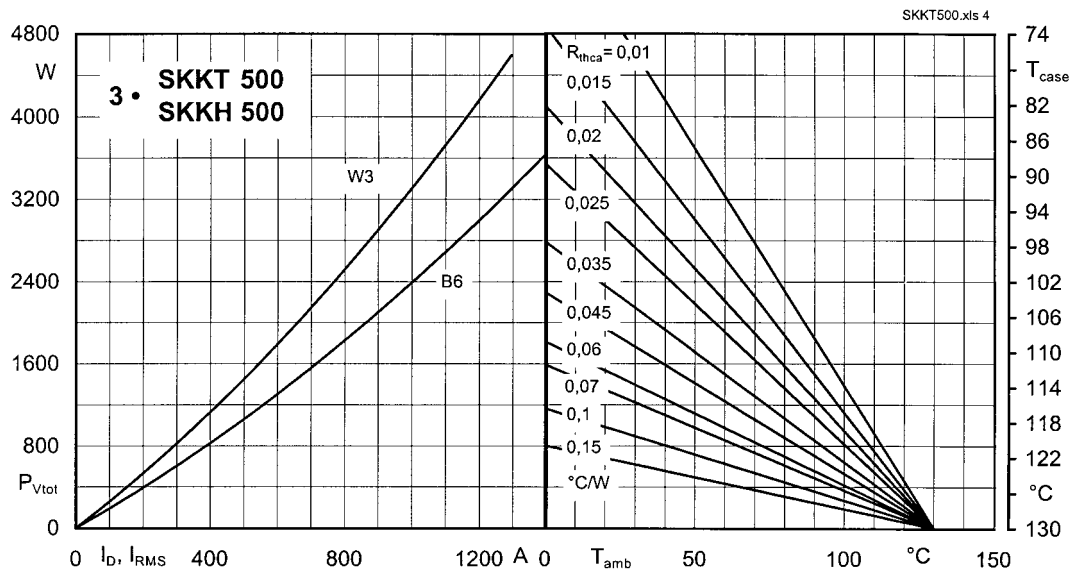


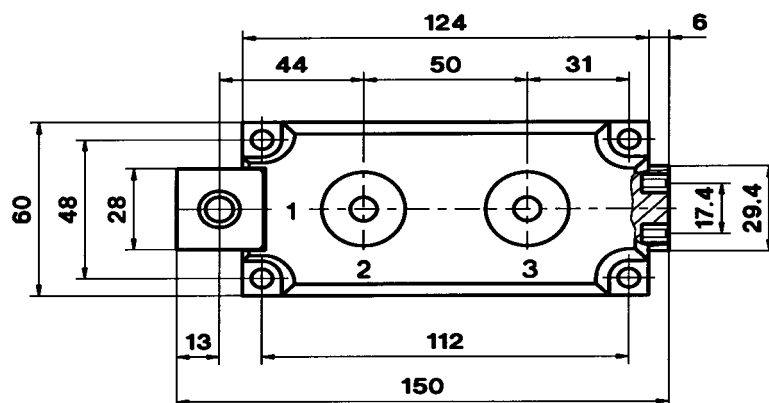
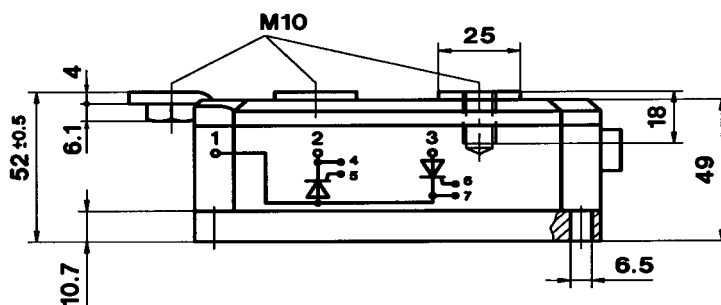
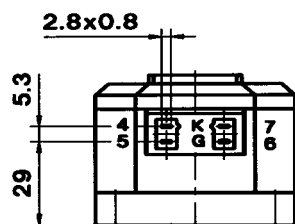
Fig. 4 Power dissipation of three modules vs. direct and rms current and case temperature

SKKT 500

Case A 60

SEMIPACK® 5

UL recognition, file E63532
applied for



Dimensions in mm